

# PFM Mode Step-Up DC/DC Converter With True Shutdown

# **■ FEATURES**

- Adjustable Output Voltage up to 24V.
- 2.7V to 5.5V Input Range.
- Maximum 0.1µA Shutdown Current.
- Tiny Inductor and Capacitors are allowed.
- Space-Saving SOT-23-6 Package.

# APPLICATIONS

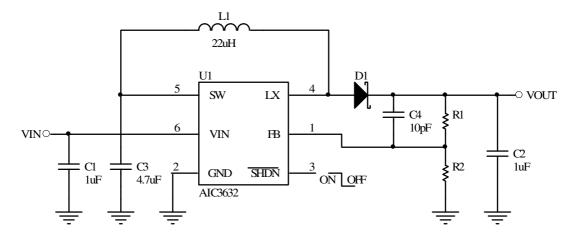
- LCD Bias
- LCM
- OLED Driver

### DESCRIPTION

AIC3632 is a pulse-frequency modulation (PFM), step-up DC/DC Converter. The built-in high voltage N-channel MOSFET allows AIC3632 for step-up applications with up to 24V output voltage, as well as for Single Ended Primary Inductance Converter (SEPIC) and other low-side switching DC/DC converter.

The AIC3632 is available in a space-saving SOT-23-6 package.

# **■ TYPICAL APPLICATION CIRCUIT**



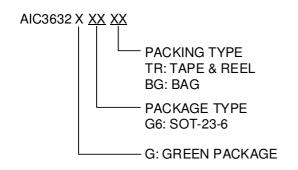
**Typical Application Circuit** 

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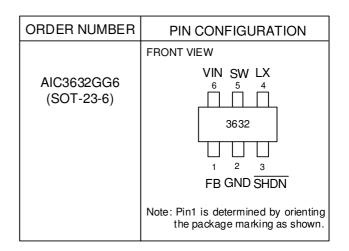


# ORDERING INFORMATION



Example: AIC3632GG6TR

→ in SOT-23-6 Green Package and Tape & Reel Packing Type



# SOT-23-6 Marking

| Part No.   | Marking |  |
|------------|---------|--|
| AIC3632GG6 | 3632G   |  |

## ■ ABSOLUTE MAXIMUM RATINGS

| LX to GND   | 28V          |
|---|--------------|
| FB to GND   |              |
| VIN, SW, SHDN   | 6V           |
| SW Pin RMS Current                                    | 0.6A         |
| Operating Ambient Temperature Range T <sub>A</sub>    | -40℃ to 85℃  |
| Operating Maximum Junction Temperature T <sub>J</sub> | 125℃         |
| Storage Temperature Range T <sub>STG</sub>            | -65℃ to 150℃ |
| Lead Temperature (Soldering 10 Sec.)                  | 260℃         |
| Thermal Resistance Junction to Case SOT-23-6          | 115°C/W      |
| Thermal Resistance Junction to Ambient SOT-23-6       | 250°C/W      |
| (Assume no Ambient Airflow, no Heatsink)              |              |

Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

# ■ TEST CIRCUIT

Refer to "TYPICAL APPLICATION CIRCUIT".



# ■ ELECTRICAL CHARACTERISTICS

 $(V_{IN}=V_{\overline{SHDN}}=3.6V, SW=Open, T_A=25^{\circ}C, unless otherwise specified) (Note 1)$ 

| PARAMETER                            | SYMBOL               | CONDITIONS                              | MIN    | ТҮР   | MAX    | UNITS |
|--------------------------------------|----------------------|---|--------|-------|--------|-------|
| Input Supply Range                   | V <sub>IN</sub>      |   | 2.7    |       | 5.5    | V     |
| Output Voltage Adjust Range          | V <sub>OUT</sub>     |   |        |       | 24     | V     |
| V <sub>IN</sub> Undervoltage Lockout | UVLO                 | V <sub>IN</sub> rising, 50mV hysteresis | 2.33   | 2.5   | 2.65   | V     |
| Quiescent Current                    | I <sub>IN</sub>      | V <sub>FB</sub> = 1.3V, No switching    |        | 30    | 50     | μΑ    |
| Shutdown Supply Current              |                      | $V_{\overline{SHDN}} = 0V$              |        | 0.01  | 0.5    | μΑ    |
| ERROR AMPLIFIER                      |                      |   |        |       |        |       |
| Feedback Voltage                     | $V_{FB}$             | At 0°C to 85°C, Note 1                  | 1.2076 | 1.226 | 1.2444 | V     |
| FB Input Bias Current                | I <sub>FB</sub>      | V <sub>FB</sub> = 1.24V                 | -50    |       | 50     | nA    |
| Line Regulation                      |                      | V <sub>IN</sub> = 2.7V to 5.5V          |        | 0.1   |        | %/V   |
| Load Regulation                      |                      | $V_{OUT} = 15V$ , $I_{LOAD} = 0$ to 5mA |        | 0.1   |        | %/mA  |
| OSCILLATOR                           | •                    |   |        |       |        |       |
| Misiss and Work Time                 |                      | V <sub>FB</sub> > 1.1V                  |        | 1     |        |       |
| Minimum LX Off-Time                  |                      | V <sub>FB</sub> = 0.1V                  |        | 5     |        | μS    |
| POWER SWITCH                         | •                    |   |        |       |        |       |
| On-Resistance                        | R <sub>DS(ON)</sub>  | $V_{IN} = 5V$                           |        | 0.6   | 1      | Ω     |
| Leakage Current                      | I <sub>LX(OFF)</sub> | V <sub>LX</sub> = 28V                   |        | 0.1   | 2      | μΑ    |
| Switch Current Limit                 | $I_{LX}$             |   | 0.078  | 0.101 | 0.118  | Α     |
| SOFT-START                           |                      |   |        |       |        |       |
| SW PMOS ON-Resistance                |                      | $V_{IN} = 2.7V, I_{SW} = 100mA$         |        | 1.5   | 2.5    | Ω     |
| SW PMOS Current Limit                |                      | $V_{IN} = 3.6V, V_{SW} = 0V$            | 0.4    | 0.85  | 1.1    | Α     |
| SW PMOS Leakage Current              |                      | $V_{IN} = 5.5V, V_{SW} = 0V$            |        |       | 1      | μΑ    |
| SW PMOS Soft Start Time              |                      | $V_{IN} = 2.7V, C_{SW} = 4.7\mu F$      |        | 0.2   | 1      | mS    |
| CONTROL INPUT                        | •                    |   |        |       |        |       |
| SHDN Input Low Voltage               | V <sub>IL</sub>      |   |        |       | 0.7    | V     |
| SHDN Input High Voltage              | V <sub>IH</sub>      |   | 1.5    |       |        | V     |
| SHDN Input Current                   | I <sub>SHDN</sub>    | $V_{\overline{SHDN}} = 0V$              |        | 0.01  | 0.1    | μΑ    |

**Note 1:** Specifications are production tested at T<sub>A</sub>=25°C. Specifications over the -40°C to 85°C operating temperature range are assured by design, characterization and correlation with Statistical Quality Controls (SQC).



# ■ TYPICAL PERFORMANCE CHARACTERISTICS

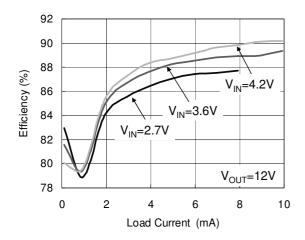


Fig. 1 Efficiency vs. Load Current

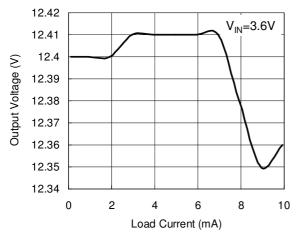


Fig. 3 Output Voltage vs. Load Current

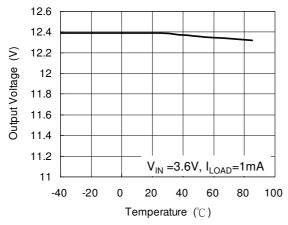


Fig. 5 Output Voltage vs. Temperature

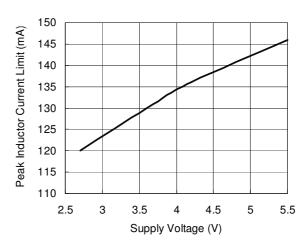


Fig. 2 Peak Inductor Current Limit vs. Supply Voltage

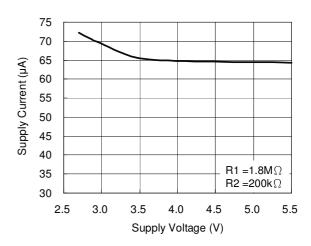


Fig. 4 Supply Current vs. Supply Voltage

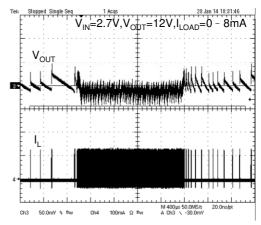


Fig. 6 Load Transient Response



# **■ TYPICAL PERFORMANCE CHARACTERISTICS(Continued)**

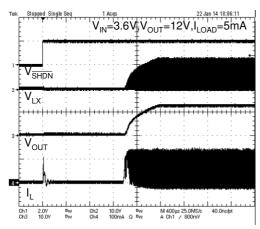


Fig. 7 Start Up Waveform

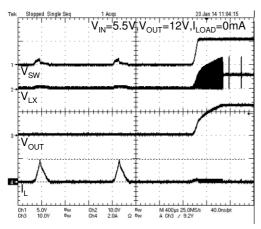


Fig. 9 Short Circuit Release

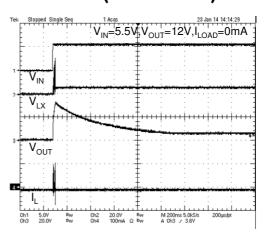
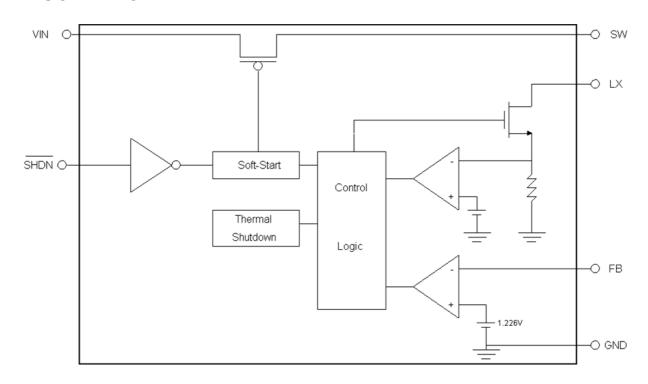


Fig. 8 Over Voltage Protection



# BLOCK DIAGRAM



# ■ PIN DESCRIPTIONS

PIN 1: FB - Feedback Input. Connect a resistive voltage divider from the output to FB to set the output voltage.

PIN 2: GND - Ground.

PIN 3: SHDN - Shutdown Input. Drive SHDN low to turn off the converter. To automatically start the converter, connect SHDN to IN. Do not leave SHDN unconnected.

PIN 4: LX - Inductor Switching Connection.

PIN 5: SW - Power Switching Connection.

Connect SW to inductor and output rectifier. Keep the distance between the components as close to SW as possible.

PIN 6: VIN - Internal Bias Voltage Input.

Connect VIN pin to the input voltage source. Bypass VIN to GND with a capacitor sitting as close to VIN pin as possible.



# APPLICATION INFORMATION

The AlC3632 is a step-up DC-DC converter. It is based on PFM control topology. At the beginning of each switching cycle, the main switch (NMOS) is turned on and the inductor current starts to ramp. When the sensing current signal equals the main switch current limit value, the main switch is turned off and the inductor current flows through diode to supply the output. The AlC3632 has true-shutdown feature which has an internal P-channel MOSFET connecting from VIN pin to SW pin to protect main switch, diode and inductor during operation period. The AlC3632 can operate with an input voltage from 2.7V to 5.5V and adjustable output voltage up to 24V.

#### **Device Shutdown**

When SHDN pin is set logic high, the AlC3632 is put into active mode operation. If SHDN pin is set logic low, the device is put into shutdown mode and consumes less than 0.5µA of current. At the shutdown mode, the internal P-channel MOSFET will turn off and the output voltage of AlC3632 step-up converter will reduce to 0V.

#### **Under-Voltage Lockout**

Under-Voltage Lockout (UVLO) prevents the main switch from turning on until input voltage exceeds 2.5V typically. When the main switch turns on, if the input voltage drops below 2.4V typically, UVLO shuts off the main switch.

#### **Adjustable Output Voltage**

An external resistor divider is used to set the output voltage. The output voltage of the switching regulator  $(V_{OUT})$  is determined by the following equation:

$$V_{OUT} = V_{FB} \times \left(1 + \frac{R_1}{R_2}\right)$$

Where V<sub>FB</sub> is 1.226V reference voltage.

#### **Short Circuit Protection**

While the output is shorted to ground, the surge current will flow through the internal P-channel MOSFET. If the surge current reaches the PMOS current limit, the internal P-channel MOSFET will turn off and restart soft-start. This would protect the inductor and diode from damage and make sure downstream circuits are safe.

#### Soft-Start

The AlC3632 has soft-start function it can prevent large inrush current during start-up period. During soft-start period, the internal P-channel switch will turn on slowly.

#### **Over Voltage Protection**

If the feedback resistor is floating or other situation is happened to make the output voltage over normal voltage, the AIC3632 will stops switching, and the output voltage will reduce to VIN voltage.

#### Inductor Selection

A  $22\mu H$  inductor is recommended for most AlC3632 applications. It is important to ensure the inductor saturation current value exceeds the peak value of inductor current in application to prevent core saturation.

#### **Diode Selection**

Schottky diodes, with their low forward voltage drop and fast reverse recovery, are the ideal choices for AlC3632 applications. The forward voltage drop of an Schottky diode represents the conduction losses in the diode, while the diode capacitance (CT or CD) represents the switching losses. For diode selection, both forward voltage drop and diode capacitance need to be considered. In addition, the rating of selected Schottky diode should be able to handle the output voltage and the maximum peak diode current.



#### **Capacitor Selection**

The small size of ceramic capacitors makes them ideal for AIC3632 applications. When choosing the input and output ceramic capacitors, low ESR/ESL X5R and X7R types are recommended because they retain their capacitance over wider ranges of voltage and temperature than other types. A 1 $\mu$ F input capacitor and a 1 $\mu$ F output capacitor are sufficient for most applications. The SW pin is suggested to connect a 4.7 $\mu$ F or greater bypass capacitor. A 10pF feed-forward capacitor connected between output and FB pin is recommended, it can improve stability for most applications.

#### **PCB Layout Guidance**

This is a considerably high frequency for DC-DC converters. PCB layout is important to guarantee satisfactory performance. It is recommended to make traces of the power loop, especially where the switching node is involved, as short and wide as possible. First of all, the inductor, input and output capacitor should be as close to the device as possible. Feedback and shutdown circuits should avoid the proximity of large AC signals involving the power inductor and switching node.

# APPLICATION EXAMPLE

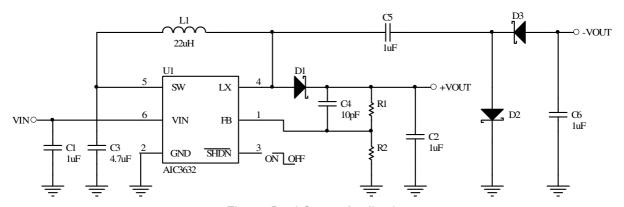
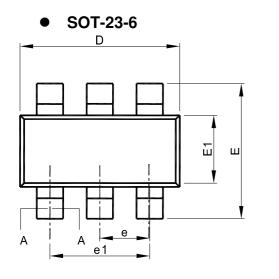
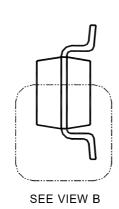


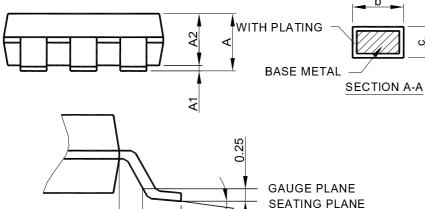
Fig. 10 Dual Output Application



# PHYSICAL DIMENSIONS (unit: mm)







| A-A | M B O L | 001 200 |       |  |
|-----|---------|---------|-------|--|
|     |         | MILLIM  | ETERS |  |
|     | O<br>L  | MIN.    |       |  |
|     | Α       | 0.95    |       |  |
|     | A1      | 0.00    |       |  |
|     | A2      | 0.90    |       |  |
|     | b       | 0.30    |       |  |
|     | С       | 0.08    |       |  |
|     | D       | 2.80    |       |  |
|     | Е       | 2.60    |       |  |
|     | E1      | 1.50    |       |  |
|     |         |         |       |  |

Note: 1. Refer to JEDEC MO-178AB.

VIEW B

- 2. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion or gate burrs shall not exceed 10 mil per side.
- 3. Dimension "E1" does not include inter-lead flash or protrusions.
- 4. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.

| A1 | 0.00     | 0.15 |  |
|----|----------|------|--|
| A2 | 0.90     | 1.30 |  |
| b  | 0.30     | 0.50 |  |
| С  | 0.08     | 0.22 |  |
| D  | 2.80     | 3.00 |  |
| Е  | 2.60     | 3.00 |  |
| E1 | 1.50     | 1.70 |  |
| е  | 0.95 BSC |      |  |
| e1 | 1.90 BSC |      |  |
| L  | 0.30     | 0.60 |  |
| L1 | 0.60 REF |      |  |
| θ  | 0°       | 8°   |  |
|    |          |      |  |

SOT-23-6

MAX. 1.45

#### Note:

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